



[Boletín de la Sociedad Chilena de Química](#)

Print version ISSN 0366-1644

Bol. Soc. Chil. Quím. vol.45 n.4 Concepción Dec. 2000

<http://dx.doi.org/10.4067/S0366-16442000000400013>

A NEW STRUCTURAL MODIFICATION OF STANNITE

*Jaime Llanos^a, Myriam Tapia^a, Carlos Mujica^a,
Judith Oró-Sole^b, and Pedro Gómez-Romero^b*

^aDepartamento de Química, Facultad de Ciencias, Universidad Católica del Norte,
Casilla 1280, Antofagasta, Chile

^bInstitut de Ciència de Materials de Barcelona (CSIC), Campus de la
Universitat Autònoma
de Barcelona, 08193 Bellaterra, Barcelona, España.

(Received: July 6, 2000 - Accepted: August 14, 2000)






ABSTRACT

The crystal structure of the phase α -SnCu₂FeS₄, has been examined by EDX and electron and X-ray diffraction techniques. This compound crystallizes in the tetragonal space group P4 (No. 81) with $a=c=541.4$ (4) pm, $Z=1$, and it is a derivative structure of the basic sphalerite structure. The refinement of the structure converged to the final agreement index $R(F)=0.060$.



Keywords: chalcogenides, electron diffraction, electron microscopy, X-ray diffraction

Services on Demand

Article

-  Article in xml format
-  Article references
-  How to cite this article
-  Automatic translation
-  Send this article by e-mail

Indicators

-  Cited by SciELO
-  Access statistics

Related links

Share

More 

More

 Permalink

RESUMEN

La estructura cristalina de la fase α -SnCu₂FeS₄ ha sido analizada por técnicas de difracción de rayos-X, electrones y Energía Dispersiva de Rayos-X. Este compuesto cristaliza en el sistema tetragonal, grupo espacial P4 (No. 81) with $a=c=541,4(4)$ pm, $Z=1$ y puede ser descrita como una estructura derivada de la esfalerita. El refinamiento final de la estructura convergió a $R(F)=0,060$.

Palabras Claves: calcogenuros, difracción de electrones, microscopía electrónica, difracción de rayos-X.

INTRODUCTION

Ternary and quaternary chalcogenides have attracted growing interest in recent years due to their physical and chemical properties, which are very promising in important technologies such as nonlinear optics, solar energy conversion, cathodes in electrochemical cells ([1-4](#)).

In previous papers, we have reported on the solid state chemistry of alkali or alkali earth metals copper-iron-chalcogenides ([5-8](#)). As a result of an attempt to prepare substitutional solid solutions in the Sn-Cu-Fe-S system we have found a new structural modification of the stannite SnCu₂FeS₄ ([9](#)).

EXPERIMENTAL

Crystal of α -SnCu₂FeS₄ were obtained by solid state reaction of SnS, Aldrich, (0.37 g) and CuFeS₂ (0.92 g). The mixture was heated in a tightly sealed graphite crucible at 1323K in a vertical furnace for 24 h under an Ar atmosphere. The sample was then allowed to cool over a period of 50 h at room temperature. The components of the sample were determined by qualitative XEDS analysis and the crystal structure determination by both electron and X-ray diffraction.

Chalcopyrite was synthesized by sulfurization of a stoichiometric mixture of copper oxide (Baker Reagents) and iron (Merck) with CS₂ as sulfiding agents carried by Ar. The mixture was pressed into a pellet and heated at 775 K by 12 h.

Electron diffraction patterns and chemical analyses were obtained using a JEOL JEM 1210 microscope operating at 120kV equipped with a side-entry 60°/30° double tilt GATHAN 646 analytical specimen holder and a link QX2000 EDX element analysis system. The specimen for electron microscopy were prepared by grinding the powder sample, dispersing it in n-butanol and depositing a droplet of this suspension on a carbon coated film supported on an alumina grid.

The data for the crystal structure determination of α -SnCu₂FeS₄ were obtained with the four circles diffractometer Enraf-Nonius CAD4 using graphite monochromated Mo K α ($\lambda =71.069$ pm) radiation.

The EDX measurements confirm the presence of the four elements, Sn, Cu, Fe, and S in the α -SnCu₂FeS₄ single crystal. [Figure 1](#) shows and EDX curve for α -SnCu₂FeS₄ single crystal.

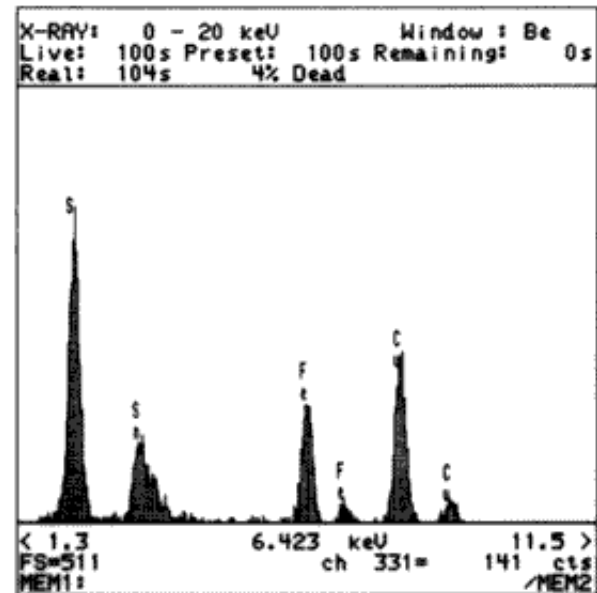


Fig.1. EDX curve for α -SnCu₂FeS₄ single crystal

Electron diffraction studies of this sample and the subsequent reconstruction of the reciprocal lattice indicates that there not any systematic absences, thus corresponding to an extinction symbol P₋. [Figure 2](#) shows the electron diffraction pattern for α -SnCu₂FeS₄ single crystal.

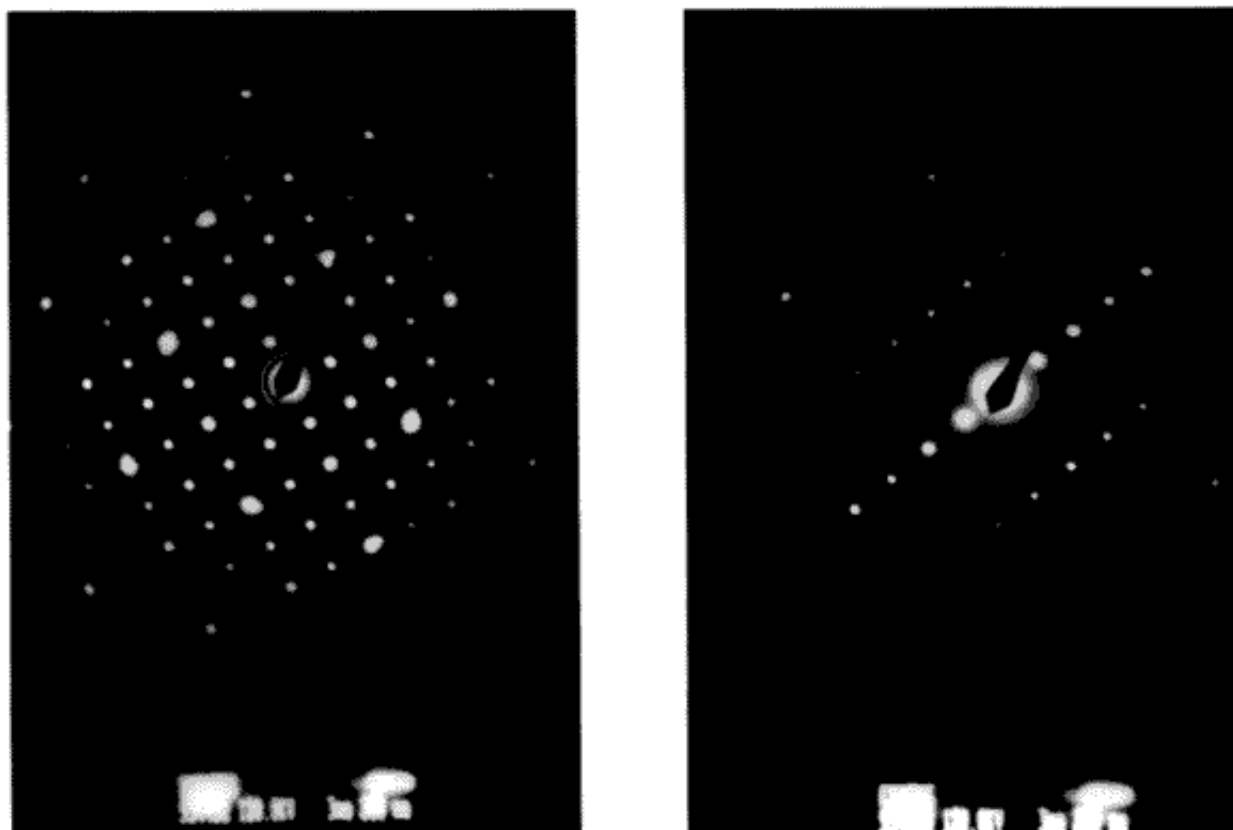


Fig.2. Electron diffraction pattern for a crystal of α -SnCu₂FeS₄

On the other hand, a crystal of α -SnCu₂FeS₄ was selected and mounted into a glass capillary for X-ray analysis with a four circles diffractometer. Cell parameters were refined from 25 centered reflections. Intensities were measured in the ω -2 θ scan mode and the absorption correction was done empirically by γ -scanning.

The structure was solved by the direct method in the space group $\bar{P}4$ and subsequently refined by the full least-squares method using the SHELXL-97 program system ([10](#)). The anisotropic refinement converged to R=0.060.

The crystallographic data as well as details of the structure analysis of α -SnCu₂FeS₄ are given in [Table 1](#).

Table I. Crystallographic Data and Details of the Structure Analysis for α -SnCu₂FeS₄

Formula	SnCu ₂ FeS ₄
Crystal system	Tetragonal
Space group	P4 (No. 81)
a (pm)	541.4 (3)
c (pm)	541.4 (3)
Z	1
Volume (10 ⁶ pm ³)	158.61 (5)
μ MoK α (mm ⁻¹)	22.44
ρ (g cm ³)	5.416
Diffractometer	Enraf Nonius CAD 4
Radiation, monochromator	Mo K α , highly oriented graphite crystal
Temperature of measurement (K)	298
θ max. (°)	full hemisphere
Index range	-7 ≤ h ≤ 7, -7 ≤ k ≤ 7, -7 ≤ l ≤ 7
Measured reflections	1932
Unique reflections	487
Number of refined parameters	20
S= goodness of fit	1.09
Final R ^a	0.060

$$^a R = \frac{\sum (|F_o| - |F_c|)}{\sum |F_o|}$$

RESULT AND DISCUSSION

The refined atomic coordinates, equivalent displacement factors and site occupation are given in [Table 2](#). Selected interatomic distances and angles are given in [Table 3](#). The crystal structure, plotted using the program *CrystalMaker 4.0* ([11](#)), is shown in [Fig. 3](#).

Table II. Fractional Atomic Coordinates, and Equivalent Displacement Parameters (in pm²).

Atom	Position	x	y	z	S.O.F.	U_{eq}^a
Sn	1a	0	0	0	1	26(6)
Cu	2g	0	1/2	0.5003(8)	1	180(7)
Fe	1c	1/2	1/2	0	1	105(7)
S	4h	0.2552(3)	0.2551(3)	0.2554(4)	1	70(8)

^a U_{eq} is defined as one third of the trace of the orthogonalized U_{ij} tensor

Table III. Selected Interatomic Distances (pm) and Angles (°) with Standard Deviation in Parentheses.

Interatomic distances		Bond angles	
Cu-S	232.9 (3) x 2 232.7 (3) x 2	S-Cu-S	110.6 (3) x 2 107.2 (3) x 2
Fe-S	232.9 (4) x 4	S-Fe-S	110.6 (3) x 2 107.2 (3) x 2
Sn-S	239.3 (3) x 4	S-Sn-Cu	109.4 (2) x 4

The structure of α -SnCu₂FeS₄, is a normal tetrahedral compound which may be regarded as a derivative of the basic sphalerite structure. As it is expected for this type of structure, each S atom is surrounded by four cations (two Cu, one Fe and one Sn), and each cation is coordinated by four sulfur atoms. The tetrahedra surrounding the Sn atoms are the most regular.

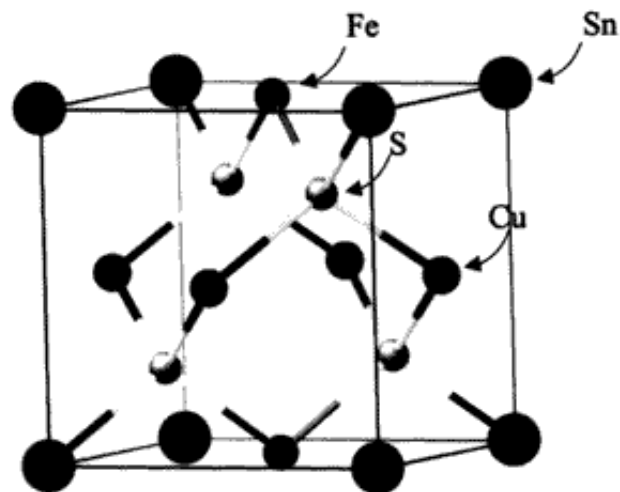


Fig.3. Unit cell of of α - $\text{SnCu}_2\text{FeS}_4$

Taking into account the metric of the unit cell of α - $\text{SnCu}_2\text{FeS}_4$ ($a=b=c=541.3$ pm) , the structure was first intended to solve in the following space groups: $\text{Pm}\bar{3}$ (No. 221), $\text{P43}\bar{m}$ (No. 215), P432 (No. 207), $\text{Pm}\bar{3}$ (No. 200), and P23 (No. 195). All results shown either six-fold coordination for the copper, iron, tin, and sulfur atoms or very high residual factors.

Finally, is known that the symmorphic space group for the sphalerite structure is T_d^2 (F4 3m), a study of the subgroups of the crystallographic T_d ($4 3m$) point group indicated that the lower possible symmetry was 4. Due to the electron diffraction results verify that there not any systematic absences, the structure was solved in the space group $\text{P4}\bar{}$.

ACKNOWLEDGMENTS

This work was supported by FONDECYT contract 1960372 and the Programa de Intercambio Científico CONICYT (Chile) and CSIC (Spain), grant 96022.

REFERENCES

1. R.L. Glitzendanner, and F.L Di Salvo, Inorg. Chem. 35, 2623 (1996) [[Links](#)]
2. R.A. Smith, Semiconductors, Cambridge University Press,Cambridge, 1978, p. 438 [[Links](#)]
3. M. Oledzka, K.V. Ramanujachary, and M. Greenblatt, Mater. Res. Bull. 33, 855 (1998)
4. P. Wu, M.A. Pell, J.A. Cody, and J.A Ibers, J. Alloys and Compounds, 224, 199 (1995) [[Links](#)]

5. C. Mujica, J. Páez, and J. Llanos, Mater Res. Bull., 29, 263 (1994). [[Links](#)]
 6. J. Llanos, P. Valenzuela, C. Mujica, A. Buljan, and R. Ramírez, J. Solid State Chem., 122, 31 (1996). [[Links](#)]
 7. J. Llanos, C. Mujica, O. Wittke, P. Gómez-Romero, and R. Ramírez, J. Solid State Chem., 128, 62 (1997) [[Links](#)]
 8. R. Ramírez, A. Bulján, J.C. Noya, and J. Llanos. Chem. Phys., 189, 585 (1994). [[Links](#)]
 9. G.M. Sheldrick, SHELXS-97, SHELXL-97, University of Göttingen, 1997 [[Links](#)]
 10. S.R. Hall, J.T. Szymanski, and J. M. Stewart, Can. Mineral. 16, 147 (1978) [[Links](#)]
 11. D.C. Palmer, CrystalMaker 4.0. An interactive crystallography program for Macintosh, 1999 [[Links](#)]
-



Paicaví 170, Depto. 19
Dirección Postal: Casilla 2613
Fono 41-227815, Fax 41-235819

Concepción, Chile

e-Mail

gcontrer@udec.cl